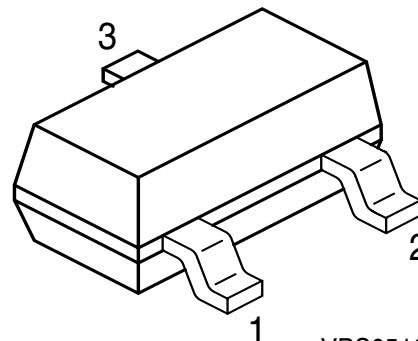


**NPN Silicon RF Transistor**

- Especially suitable for TV-Sat and UHF tuners



VPS05161

**ESD: Electrostatic discharge sensitive device, observe handling precaution!**

| Type   | Marking | Pin Configuration |       |       | Package |
|--------|---------|-------------------|-------|-------|---------|
| BF 775 | LOs     | 1 = B             | 2 = E | 3 = C | SOT-23  |

**Maximum Ratings**

| Parameter  | Symbol    | Value       | Unit             |
|--|-----------|-------------|------------------|
| Collector-emitter voltage                                | $V_{CEO}$ | 15          | V                |
| Collector-emitter voltage                                | $V_{CES}$ | 20          |                  |
| Collector-base voltage                                   | $V_{CBO}$ | 20          |                  |
| Emitter-base voltage                                     | $V_{EBO}$ | 2.5         |                  |
| Collector current  | $I_C$     | 30          | mA               |
| Base current   | $I_B$     | 4           |                  |
| Total power dissipation<br>$T_S \leq 48^\circ\text{C}^1$ | $P_{tot}$ | 280         | mW               |
| Junction temperature                                     | $T_j$     | 150         | $^\circ\text{C}$ |
| Ambient temperature                                      | $T_A$     | -65 ... 150 |                  |
| Storage temperature                                      | $T_{stg}$ | -65 ... 150 |                  |

**Thermal Resistance**

| Parameter                  | Symbol     | Value      | Unit |
|----------------------------|------------|------------|------|
| Junction - soldering point | $R_{thJS}$ | $\leq 365$ | K/W  |

<sup>1</sup> $T_S$  is measured on the collector lead at the soldering point to the pcb

### Electrical Characteristics

| Parameter   | Symbol                      | Values |      |      | Unit          |
|---|-----------------------------|--------|------|------|---------------|
|   |                             | min.   | typ. | max. |               |
| <b>Characteristics</b>  |                             |        |      |      |               |
| Collector-emitter breakdown voltage<br>$I_C = 1 \text{ mA}, I_B = 0$                  | $V_{(\text{BR})\text{CEO}}$ | 15     | -    | -    | V             |
| Collector-emitter cutoff current<br>$V_{\text{CE}} = 20 \text{ V}, V_{\text{BE}} = 0$ | $I_{\text{CES}}$            | -      | -    | 10   | $\mu\text{A}$ |
| Collector -base cutoff current<br>$V_{\text{CB}} = 10 \text{ V}, I_E = 0$             | $I_{\text{CBO}}$            | -      | -    | 100  | nA            |
| Emitter-base cutoff current<br>$V_{\text{EB}} = 2.5 \text{ V}, I_C = 0$               | $I_{\text{EBO}}$            | -      | -    | 100  | $\mu\text{A}$ |
| DC current gain<br>$I_C = 10 \text{ mA}, V_{\text{CE}} = 8 \text{ V}$                 | $h_{\text{FE}}$             | 40     | 100  | 200  | -             |

**Electrical Characteristics**

| <b>Parameter</b>   | <b>Symbol</b> | <b>Values</b> |             |             | <b>Unit</b> |
|--|---------------|---------------|-------------|-------------|-------------|
|  |               | <b>min.</b>   | <b>typ.</b> | <b>max.</b> |             |
| <b>AC Characteristics</b>  |               |               |             |             |             |
| Transition frequency<br>$I_C = 10 \text{ mA}, V_{CE} = 8 \text{ V}, f = 500 \text{ MHz}$   | $f_T$         | 3.5           | 5.5         | -           | GHz         |
| Collector-base capacitance<br>$V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$   | $C_{cb}$      | -             | 0.38        | 0.6         | pF          |
| Collector emitter capacitance<br>$V_{CE} = 10 \text{ V}, f = 1 \text{ MHz}$  | $C_{ce}$      | -             | 0.2         | -           |             |
| Emitter-base capacitance<br>$V_{EB} = 0.5 \text{ V}, f = 1 \text{ MHz}$  | $C_{eb}$      | -             | 0.5         | -           |             |
| Noise figure<br>$I_C = 2 \text{ mA}, V_{CE} = 6 \text{ V}, Z_S = Z_{\text{Sopt}}, f = 900 \text{ MHz}$<br>$f = 1.8 \text{ GHz}$  | $F$           | -             | 1           | -           | dB          |
| -  | -             | -             | 1.6         | -           |             |
| Power gain, maximum available <sup>1)</sup><br>$I_C = 10 \text{ mA}, V_{CE} = 8 \text{ V}, Z_S = Z_{\text{Sopt}}, Z_L = Z_{\text{Lopt}}, f = 900 \text{ MHz}$<br>$f = 1.8 \text{ GHz}$ | $G_{ma}$      | -             | 16          | -           |             |
| -  | -             | -             | 10.5        | -           |             |
| Transducer gain<br>$I_C = 10 \text{ mA}, V_{CE} = 8 \text{ V}, Z_S = Z_L = 50\Omega, f = 900 \text{ MHz}$<br>$f = 1.8 \text{ GHz}$   | $ S_{21e} ^2$ | -             | 13          | -           |             |
| -  | -             | -             | 7.5         | -           |             |

<sup>1)</sup> $G_{ma} = |S_{21}/S_{12}| (k - (k^2 - 1)^{1/2})$